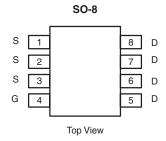




P-Channel 20-V (D-S) MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (A)			
	0.0075 at V _{GS} = - 4.5 V	- 14			
- 20	0.009 at V _{GS} = - 2.5 V	- 13			
	0.0115 at V _{GS} = - 1.8 V	- 12			



Ordering Information: Si4423DY-T1-E3 (Lead (Pb)-free)

Si4423DY-T1-GE3 (Lead (Pb)-free and Halogen-free)

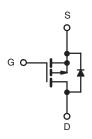
FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET[®] Power MOSFET
- Compliant to RoHS Directive 2002/95/EC

RoHS COMPLIANT HALOGEN FREE

APPLICATIONS

- · Game Station
 - Load Switch



P-Channel MOSFET

Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V_{DS}	- 20		V
Gate-Source Voltage		V_{GS}	± 8		V
Continuous Drain Current /T 150 °C\8	T _A = 25 °C	- I _D	- 14	- 10	^
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C		- 11.5	- 8	
Pulsed Drain Current		I _{DM}	- 50		Α
Continuous Source Current (Diode Conduction) ^a		I _S	- 2.7	- 1.36	
	T _A = 25 °C	P _D	3.0	1.5	W
Maximum Power Dissipation ^a	T _A = 70 °C	T I'D	1.9	0.95	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55	to 150	°C

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Maximum Junction-to-Ambient ^a	t ≤ 10 s	D	33	42		
Waximum Junction-to-Ambient	Steady State	R_{thJA}	70	84	°C/W	
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	16	21		

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

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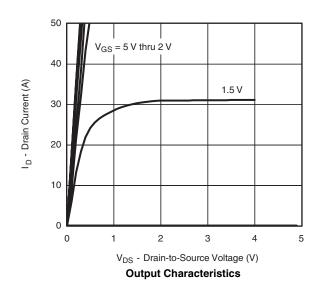
SPECIFICATIONS T _J = 25 °C, unless otherwise noted							
Parameter	Symbol	Test Conditions	onditions Min.		Max.	Unit	
Static							
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = -600 \mu A$	V _{DS} = V _{GS} , I _D = - 600 μA - 0.4		- 0.9	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 8 \text{ V}$			± 100	nA	
Zero Gate Voltage Drain Current	I _{DSS} V	V _{DS} = - 20 V, V _{GS} = 0 V			- 1		
		V _{DS} = - 20 V, V _{GS} = 0 V, T _J = 70 °C	- 1		- 10	μΑ	
On-State Drain Current ^a	I _{D(on)}	V _{DS} = - 5 V, V _{GS} = - 4.5 V	- 30			Α	
		$V_{GS} = -4.5 \text{ V}, I_D = -14 \text{ A}$		0.006	0.0075		
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = -2.5 \text{ V}, I_D = -13 \text{ A}$		0.0071	0.009	Ω	
	, ,	V _{GS} = - 1.8 V, I _D = - 12 A	0.009 0.0		0.0115	1	
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 10 V, I _D = - 14 A		60		S	
Diode Forward Voltage ^a	V_{SD}	I _S = - 2.7 A, V _{GS} = 0 V		- 0.6	- 1.1	V	
Dynamic ^b				•			
Total Gate Charge	Q_g			116	175		
Gate-Source Charge	Q_{gs}	$V_{DS} = -10 \text{ V}, V_{GS} = -5 \text{ V}, I_{D} = -14 \text{ A}$		16		nC	
Gate-Drain Charge	Q_{gd}			27		1	
Gate Resistance	R_{g}			3.2		Ω	
Turn-On Delay Time	t _{d(on)}			75	115		
Rise Time	t _r	V_{DD} = - 10 V, R_L = 10 Ω		165	250		
Turn-Off Delay Time	t _{d(off)}	$I_D\cong$ - 1 A, V_{GEN} = - 4.5 V, R_g = 6 Ω		460	700	ns	
Fall Time	t _f			210	320	113	
Source-Drain Reverse Recovery Time	t _{rr}	$I_F = -2.1 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}$		105	160		

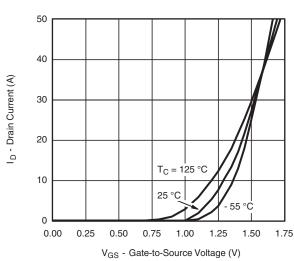
Notes:

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



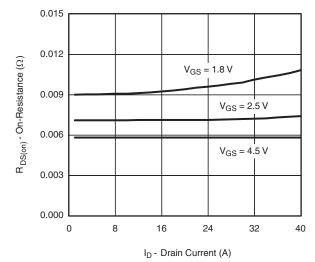


Transfer Characteristics

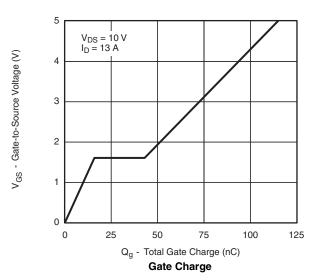


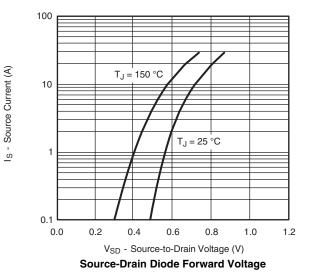


TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



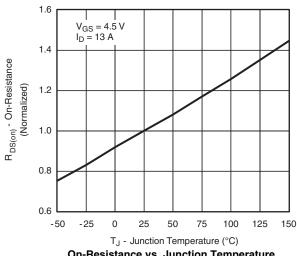
On-Resistance vs. Drain Current



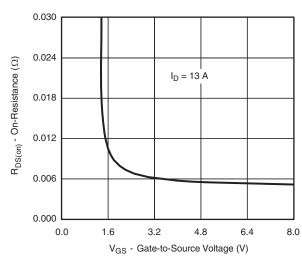


12 000 10 000 Ciss C - Capacitance (pF) 8000 6000 4000 Coss 2000 0 0 8 16 20

V_{DS} - Drain-to-Source Voltage (V) Capacitance



On-Resistance vs. Junction Temperature

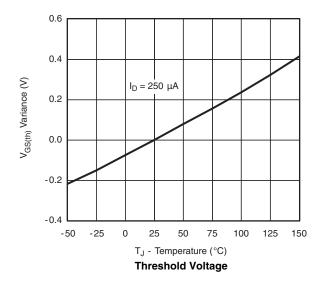


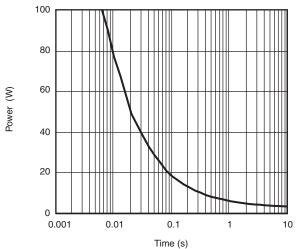
On-Resistance vs. Gate-to-Source Voltage

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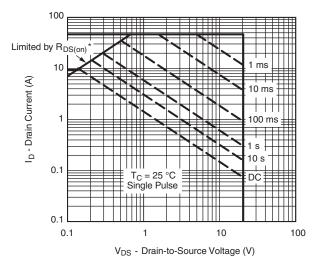
VISHAY

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

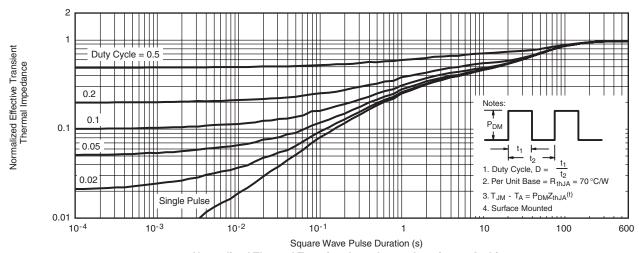




Single Pulse Power, Junction-to-Ambient



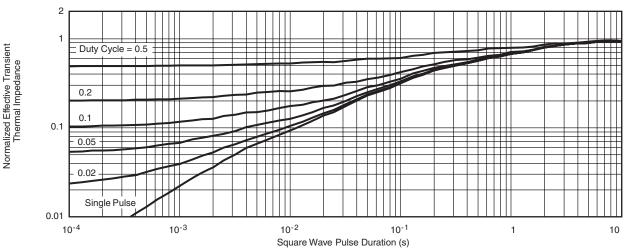
* V_{GS} > minimum V_{GS} at which R_{DS(on)} is specified **Safe Operating Area, Junction-to-Case**



Normalized Thermal Transient Impedance, Junction-to-Ambient



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

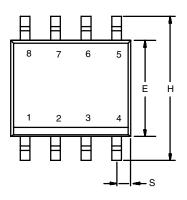


Normalized Thermal Transient Impedance, Junction-to-Foot

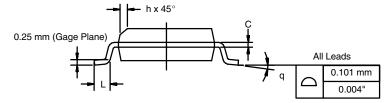
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SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012







	MILLIM	IETERS	INCHES			
DIM	Min	Max	Min	Max		
Α	1.35	1.75	0.053	0.069		
A ₁	0.10	0.20	0.004	0.008		
В	0.35	0.51	0.014	0.020		
С	0.19	0.25	0.0075	0.010		
D	4.80	5.00	0.189	0.196		
Е	3.80	4.00	0.150	0.157		
е	1.27	BSC	0.050 BSC			
Н	5.80	6.20	0.228	0.244		
h	0.25	0.50	0.010	0.020		
L	0.50	0.93	0.020	0.037		
q	0°	8°	0°	8°		
S	0.44	0.64	0.018	0.026		
ECN: C-06527-Rev. I. 11-Sep-06						

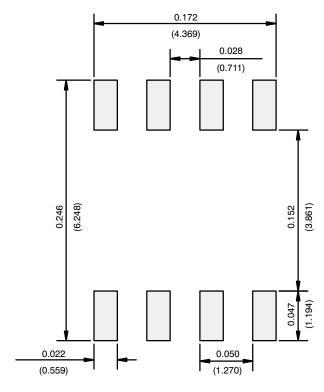
DWG: 5498

Document Number: 71192 www.vishay.com 11-Sep-06

Vishay Siliconix



RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads Dimensions in Inches/(mm)

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APPLICATION NOT

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